UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO.

: 7,399,693 B2

Page 1 of 1

APPLICA

APPLICATION NO.: 10/566170

DATED

: July 15, 2008

INVENTOR(S)

: Yoshinobu Sekiguchi

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

COLUMN 12:

Line 57, "Al_{0.13}Ga_{0.87} layer 30:" should read -- Al_{0.13}Ga_{0.87} As layer 30: --.

COLUMN 16:

Line 25, "microc-" should read -- micro- --; and Line 26, "rystalline" should read -- crystalline --.

Signed and Sealed this

Third Day of March, 2009

JOHN DOLL
Acting Director of the United States Patent and Trademark Office